## **Analog Power**

## P-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSOP-6 saves board space
- Fast switching speed
- High performance trench technology

	PRODUCT SUMMARY				
	V <sub>DS</sub> (V)	r <sub>DS(on)</sub> (OHM)	I <sub>D</sub> (A)		
	-20	$0.130 @ V_{GS} = -4.5V$	-2.5		
	-20	$0.190 @ V_{GS} = -2.5V$	-1.9		
i1		$G_1 $ $G_1 $	S₂ G₂°−−−		
2		$D_2 D_1$	D <sub>2</sub> P-Channel MOSF		

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C UNLESS OTHERWISE NOTED)						
Parame te r		Symbol	Maximum	Units		
Drain-Source Voltage		V <sub>DS</sub>	-20	V		
Gate-Source Voltage		V <sub>GS</sub>	±12	v		
Continuous Drain Current <sup>a</sup>	$T_A=25^{\circ}C$	I <sub>D</sub>	-2.5	A		
Continuous Drain Current	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	ID	-1.9			
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	-10			
Continuous Source Current (Diode Conduction) <sup>a</sup>		Is	±1.6	А		
	T <sub>A</sub> =25°C	D.	1.15	W		
Power Dissipation <sup>a</sup> P <sub>D</sub>	0.7	vv				
Operating Junction and Storage Temperature Range		TJ, Tstg	-55 to 150	°C		

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Тур	Max				
Mariana Ingeting to Amiliant <sup>a</sup>	t <= 10 sec	D	93	110			
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	R <sub>thJA</sub>	130	150	°C/W		

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)								
Parameter	Symbol	Test Conditions	Limits Min Tun May					

Parameter	Symbol		Limits			T Incid	
Farameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static			-			-	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -250 \text{ uA}$	-0.60				
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = +/-12 V$			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -16 V, V_{GS} = 0 V$			-1	uA	
Zero Gate Voltage Dram Current	1088	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ} \text{C}$			-10	uA	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 V, V_{GS} = -10 V$	-3			Α	
Drain-Source On-Resistance <sup>A</sup>		$V_{GS} = -4.5 \text{ V}, I_D = -2.5 \text{ A}$			0.130	Ω	
Drain-Source On-Resistance	r <sub>DS(on)</sub>	$V_{GS} = -2.5 \text{ V}, I_D = -1.9 \text{ A}$			0.190		
Forward Tranconductance <sup>A</sup>	g <sub>fs</sub>	$V_{DS} = -5 V, I_D = -2.5 A$		3		S	
Diode Forward Voltage	V <sub>SD</sub>	$I_{\rm S} = -1.6 \text{ A}, V_{\rm GS} = 0 \text{ V}$		-0.70		V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg	$V_{DS} = -5 V, V_{GS} = -4.5 V,$		12.2		nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -5 V, V_{GS} = -4.5 V,$ $I_D = -2.5 A$		1.1			
Gate-Drain Charge	Q <sub>gd</sub>	$I_D = -2.3 \text{ A}$		1.5			
Turn-On Delay Time	t <sub>d(on)</sub>			6.5			
Rise Time	t <sub>r</sub>	$V_{DD} = -5 V, R_L = 5 OHM,$		20		ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN} = -4.5 \text{ V}, R_G = 6 \text{ OHM}$		31			
Fall-Time	t <sub>f</sub>			21			

Notes

- a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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